NSN 5961-00-919-5885

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-919-5885

Inclosure Material:

Metal

Overall Length:

0.215 inches

Overall Diameter:

0.460 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.138 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 10.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 500.00 milliamperes source cutoff current and 750.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unc

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release3379 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

NSN 5961-00-919-5885 Transistor - Page 2 of 2

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